

## Design of Magneto-rheological Fluid Based Device

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### 자기유변유체를 이용한 공학 장치의 설계

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The effect of power supply voltage on the performance limits in a laboratory Magneto-rheological fluid based device was identified by experiments. It suggests that the frequency range of motion for control be limited by the voltage attenuation due to the coil inductance and the maximum power supply voltage set for practical use of MRF devices. In this work, the magnetic and electrical characteristics of MRF device are investigated and a design procedure is formulated to achieve the desired performance for a given power supply.

**Key Words :** Magneto-rheological Fluid (자기유변유체), Yield Stress (항복응력), Slew Rate, Power Supply Voltage (전원전압), Design Procedure (설계절차)

### 1. Introduction

Magneto-rheological fluid (MRF) changes its rheological characteristics according to the applied magnetic field strength. The fluid typically consists of micron-size, magnetically polarizable particles dispersed in a carrier medium. The formation of particle chains upon the application of a magnetic field is essential to operation of MRF[1]. In the presence of shear force, the equilibrium that is established between the formation and breaking of particle fabrics corresponds to the yield stress defined for the fluid. The controllable control force of MRF device makes use of the yield stress. This simple and easy change of its characteristics without mechanical moving parts makes it possible to provide simple, quiet, rapid-response electromechanical devices[2,3]. Thus MRF devices have attracted much attention among control and design engineers in the past decade and are considered as a technical breakthrough for 'smart' electromechanical devices, especially stress transfer and damping devices[4]. Not only their feasibility is being widely demonstrated, but also their many advantages against the conventional passive and fully active engineering devices are becoming apparent. On the other hand, it is also important to recognize and understand the shortcomings of MRF devices[5]. Among others, two

major problems occur frequently in the engineering applications of MRF. The rate at which the yield stress of MRF can change is strictly limited due to the presence of the inductance of MRF device and the fixed power supply voltage. This phenomenon is referred to as the yield stress slew rate limitation. The maximum yield stress is also subject to a strict limit due to the magnetic saturation and the fixed power supply voltage.

It has been widely known that an advantage of MRF devices is the utilization of low-voltage, current-driven power supply, unlike electro-rheological fluid which requires high voltage power supply for implementation of controllable devices[1,2,3,6,7]. MRF devices are designed to guarantee the desired maximum yield stress by avoiding the magnetic saturation and using the power supply voltage just greater than the resistance multiplied by the maximum current[8,9]. In other words, power supply is not considered explicitly in the design process of MRF device, which turns out to be inadequate to control high frequency motion. The voltage attenuation due to the coil inductance significantly increases over the high frequency range of interest. In order for the high frequency performance of the controlled motion to be enhanced, high power supply voltage is needed, since power supply voltage is one of the factors which determine the bandwidth of MRF device. But the voltage level of power supply for MRF device is, in practice, limited mainly due to cost, and thus power supply voltage is predetermined in the design process of MRF device.

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## 2. Motivation

In order to investigate the effect of the power supply voltage on the performance of MRF device, a rotary MRF damper developed in the laboratory[10,11] for electronically controlled power steering, as shown in Figure 1, is considered. Since the yield stress of MRF in the device is difficult to be directly measured, the control current delivered to the device was observed instead during the experiments, since the yield stress of MRF can be estimated from the measured control current. For the experiments, a uni-directional current amplifier with gain of 1 A/V was manufactured in the laboratory. For comparison, two loads were applied for two types of control commands: 7.6 ohm and 3.73 mH @ 120 Hz for load #1 and 5.1 ohm and 7.81 mH @ 120Hz for load #2. The sinusoidal and step control commands of 100 Hz to the uni-directional current amplifier were given, respectively, by

$$V_C = I = 0.5 + 0.5\sin(200\pi t), \quad (1)$$

$$V_C = I = 1, \text{ if } \sin(200\pi t) > 0, \text{ else } V_C = I = 0. \quad (2)$$

where  $V_C$  is the control input voltage. Figures 2 and 3 show the control currents delivered to load #1 and #2, respectively, for the sinusoidal control command. For load #1, the current followed the control voltage well. when the power supply voltage of 15 V was applied. But for load #2, the desired power supply voltage dropped to 13.7 V. Note that since load #2 has a resistance smaller than load #1, the desired maximum current amplitude can be achieved with a lower power supply voltage than load #1. In this case, the resistance of a device determines the necessary power supply voltage. On the other hand, for the step control command having higher frequency components than the sinusoidal control command, load #2 of a higher inductance requires a higher power supply voltage to follow the control current for the step control command as shown in Figures 4 and 5. The control current in load #2 cannot rise as fast as that in load #1. Thus the desired bandwidth of the current should be increased to follow the control command, requiring power supply voltage higher than about 15 volts. In this case, the inductance of a device determines the necessary power supply voltage. In other words, as the load becomes severer, larger power supply voltage is needed.

In practice, we often increase the number of coil turns in order to reduce the necessary maximum control current, which increases the inductance of MRF device. This, in turn, increases the necessary power supply voltage as the frequency range of interest increases. Thus, the mechanisms which limit the performance of MRF device

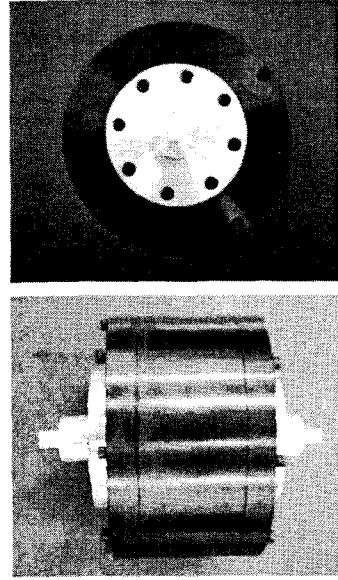


Figure 1. Rotary MR Damper for Electronically Controlled Power Steering [Jung and Park, 1998 and 1999]

should be investigated in order to predict the performance limits with a given power supply and to formulate a design procedure to achieve the desired performance of the device as a whole, which will be discussed in the following sections.

## 3. Governing Equations of MRF Device

### Mechanical Dynamic Model

The dynamic behavior of MRF is often modeled as the Bingham plastic model given by[4]

$$\begin{aligned} \tau &= \tau_y \text{sign}(\dot{\gamma}) + \eta_p \dot{\gamma}, & \text{for } |\tau| \geq |\tau_y| \\ \dot{\gamma} &= 0, & \text{for } |\tau| < |\tau_y| \end{aligned} \quad (3)$$

where  $\tau$  is the shear stress;  $\tau_y$  is the dynamic yield stress which is an increasing function of the magnetic field strength  $H$ ;  $\eta_p$  is the plastic viscosity and  $\dot{\gamma}$  is the shear rate. Apparent viscosity,  $\eta_a \equiv \tau/\dot{\gamma}$ , increases as the applied magnetic field strength and thus  $\tau_y$  increases. The expression of  $\tau_y$  in exponential form is usually used in the design process as

$$\tau_y = \alpha H^\beta \quad (4)$$

where  $\alpha$  is the proportionality coefficient determined from experiment and  $\beta$  is the exponent conventionally known as similar to 2. Two basic operational modes used for MRF devices are the valve and shear modes, as

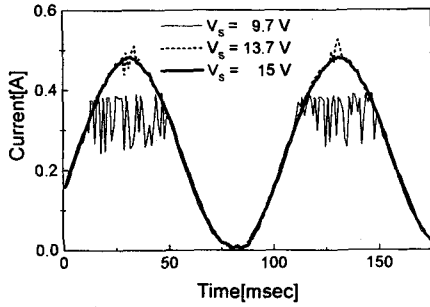


Figure 2. Control Current to Sinusoidal Control Voltage in Load 1

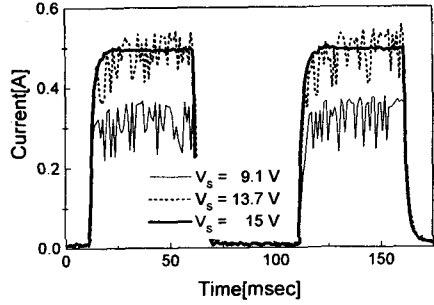


Figure 4. Control Current to Step Control Voltage in Load 1

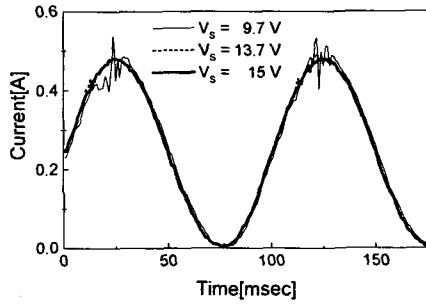


Figure 3. Control Current to Sinusoidal Control Voltage in Load 2

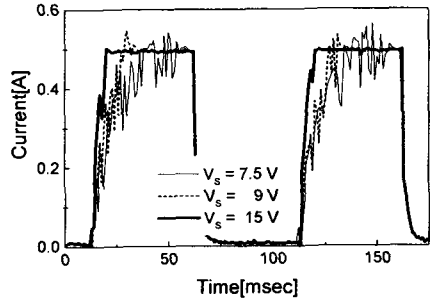


Figure 5. Control Current to Step Control Voltage in Load 2

shown in Figure 6. Design equations for a device utilizing either the valve or shear mode are derived using Eq. (3)[1,2,3]. The pressure drop,  $\Delta P$ , in valve mode is obtained as[9,12]

$$\Delta P = \frac{12\eta_p l}{g^3 w} Q + \frac{Cl}{g} \tau_y \quad (5)$$

where  $l$  and  $w$  are the length and width of the pole, respectively;  $g$  is the gap between the two poles;  $Q$  is the volume flow rate;  $C$  is the experimentally determined constant parameter ranging from a minimum value of 2 to a maximum value of 3. The resisting force,  $F$ , in shear mode is also obtained as[9,12]

$$F = \frac{lw\eta_p}{g} S + lw\tau_y \quad (6)$$

where  $S$  is the relative speed of a pole to another. Note that, as Eqs. (5) and (6) indicate, the controllable force, pressure drop  $\Delta P$  or resisting force  $F$ , of MRF device is proportional to the yield stress of MRF. The desired maximum yield stress,  $\tau_y^*$ , and the plastic viscosity,  $\eta_p$ , govern the volume of MRF necessary to achieve the required controllable force[1,2,3].

### Magnetic Circuit

A simple magnetic circuit can provide the field strength needed to activate and control MRF as shown in Figure 7. The basic relations with the assumption of no magnetic saturation become[2,3,8]

$$B_S A_S = B_g A_g \quad (7)$$

$$H_S l_S (\approx 0) + H_g l_g = NI \quad (8)$$

where  $B$  is the flux density;  $l$  is the flux path length;  $A$  is the cross sectional area;  $I$  is the current;  $N$  is the number of coil turns. The subscripts  $S$  and  $g$  denote the steel and gap, respectively. The flux path length and cross sectional area of gap determine the amount of steel required to achieve the desired field strength and yet to avoid magnetic saturation as in Eq. (7). The flux path length in MRF,  $l_g$ , is a linear function of the gap,  $g$ , whose concrete form is determined according to the application. The reluctance of steel is much less than that of MRF and thus it can be neglected in the design process as in Eq. (8).

The most immediately apparent limiting behavior of MRF devices is the maximum controllable force

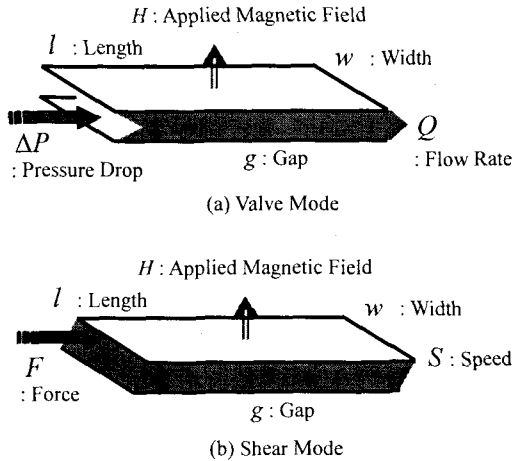


Figure 6. Basic Operational Modes [Carlson et al., 1995]

limitation, or, equivalently, the maximum yield stress limitation. This limitation is primarily due to saturation in magnetization of electromagnet core materials. Eq. (8) is based on the assumption that core magnetic flux is nearly proportional to magneto motive force (MMF : coil turns  $\times$  coil current). This relationship is valid as long as the magnetic reluctance of the core is much less than that of MRF in the gap. In a typical magnetic induction vs. magnetic field curve for conventional magnet iron, the reluctance is inversely proportional to the slope of the curve. A significant feature is the leveling of the curve at high MMF's; beyond a certain point, the reluctance increases drastically. This phenomenon is referred to as magnetic saturation and the flux density at which it occurs is called the saturation flux density, which typically ranges between 1.2 and 1.6 Tesla. The effect of magnetic saturation is that, once a certain coil current is reached, further increases in current will produce relatively little increase in the yield stress of MRF[13]. Thus, in a conventional design process, the maximum yield stress of MRF, or the maximum controllable force of MRF device, is developed at the magnetic saturation of steel, i.e.

$$B_{sat} A_S = \mu_{MRF} \frac{A_g}{l_g} NI^* \quad (9)$$

where  $B_g = \mu_{MRF} H_g$ ;  $I^*$  is the maximum available current in current amplifier;  $B_{sat}$  is the saturation flux density of steel; and  $\mu_{MRF}$  is the magnetic permeability of MRF. So far, magnetic circuit design was carried out using Eq. (9) merely to maintain sufficient cross section of steel so that magnetic saturation can be avoided. From Eqs. (4) and (9), we can conclude that the maximum

yield stress of MRF device is limited by the maximum current of power supply for other design variables given.

### Electric Circuit

The electric circuit is designed to guarantee both the adequate bandwidth for effective control of MRF devices and the desired current. The output stage of the current amplifier which drives the coil is described in Figure 8[13], i.e.

$$V_S = (R + R_V + R_F)I + L \frac{dI}{dt} + V_0 \quad (10)$$

where  $R$  and  $L$  are the electrical coil resistance and inductance of solenoid which induces magnetic field in MRF, respectively;  $R_V$  is the variable resistance between the coil and ground, which varies between about 0.5 and nearly infinite ohms and is a function of  $V_C$ ;  $R_F$  is the current sensing resistance;  $V_S$  is the power supply voltage;  $V_0$  is the additional voltage of about 5 to 6 volts required for compensation of the voltage drop which can take place in the electric circuit depending upon the type of the current amplifier.

The yield stress slew rate of MRF is limited because the magnet coil is inductive and the power supply voltage to drive current amplifier is finite. The slew rate limitation causes the controllable force of MRF device to lag the control signal demands, introducing a phase lag. To reduce the phase lag or to guarantee an adequate bandwidth of MRF device for control, there should be a lower limit for power supply voltage[13].

Until now, we investigated three models which govern behaviors of MRF device and found the mechanisms which give rise to the yield stress and slew rate limitations. So, in the following discussion, a design procedure will be established in order to achieve the desired maximum yield stress and the desired maximum slew rate for the predetermined power supply voltage. This is essential for the practical MRF device, because, in practice, maximum available power supply voltage is predetermined and it is hard to increase the voltage optionally.

## 4. Design Procedure

### Magnetic Circuit Design

It will prove convenient to assume that, in the design process,  $\tau_y^*$  is given instead of the desired maximum controllable force. In addition, it is natural to assume that

the values of  $\tau_y^*$ ,  $\left(\frac{d\tau_y}{dt}\right)^*$ ,  $\alpha$ ,  $\beta$ ,  $B_{sat}$ ,  $\mu_{MRF}$ ,

$\mu_{Steel}$ ,  $R_V^*$ ,  $R_F$ ,  $V_0$ ,  $I^*$  and  $V_S^*$  are known a priori.

Here,  $\left(\frac{d\tau_y}{dt}\right)^*$  is the desired maximum yield stress

slew rate;  $R_V^*$  is the minimum value of  $R_V$ ; and  $V_S^*$  is the maximum power supply voltage. Then the design variables of the magnetic circuit become  $l_g$ ,  $A_S$ ,  $A_g$  and  $N$ . From Eqs. (4) and (9), we can easily obtain

$$\tau_y \Big|_{\max} = \alpha \left( \frac{NI^*}{l_g} \right)^\beta = \alpha \left( \frac{B_{sat}}{\mu_{MRF}} \frac{A_S}{A_g} \right)^\beta \geq \tau_y^* \quad (11)$$

where  $\tau_y \Big|_{\max}$  is the maximum available yield stress in MRF device. Eq. (11) means that it is important to maintain the sufficiently large cross section of steel in order to keep the magnetic field strength as desired. On the other hand, from Eqs. (9) and (11), we can easily obtain

$$\frac{N}{l_g} \frac{A_g}{A_S} \geq \frac{B_{sat}}{\mu_{MRF}} \frac{1}{I^*} \quad (12)$$

and

$$\frac{N}{l_g} \geq \frac{1}{I^*} \left( \frac{\tau_y^*}{\alpha} \right)^{\frac{1}{\beta}} \quad (13)$$

### Electric Circuit Design

From Eqs. (4) and (8), the desired current slew rate can be obtained as,

$$\left. \frac{d\tau_y}{dt} \right|_{\max} = \alpha \beta \left( \frac{NI^*}{l_g} \right)^{\beta-1} \frac{dI}{dt} \geq \left( \frac{d\tau_y}{dt} \right)^* \quad (14)$$

where  $\left. \frac{d\tau_y}{dt} \right|_{\max}$  is the maximum available yield stress slew rate in MRF device.

$$\frac{dI}{dt} \geq \frac{NI^*}{l_g \beta \tau_y^*} \left( \frac{d\tau_y}{dt} \right)^* \quad (15)$$

Substituting Eq. (15) into Eq. (10), we obtain

$$V_S^* \geq (R + R_V^* + R_F) I^* + L \frac{NI^*}{l_g \beta \tau_y^*} \left( \frac{d\tau_y}{dt} \right)^* \quad (16)$$

It is generally accepted that the electrical coil resistance and inductance,  $R$  and  $L$ , are proportional to the number of coil turns,  $N$ , and the square of the number of coil turns,  $N^2$ , respectively, i.e.

$$R = k_R N \quad (17)$$

$$L = k_L N^2 \quad (18)$$

where  $k_R$  and  $k_L$  are constants depending on the coil

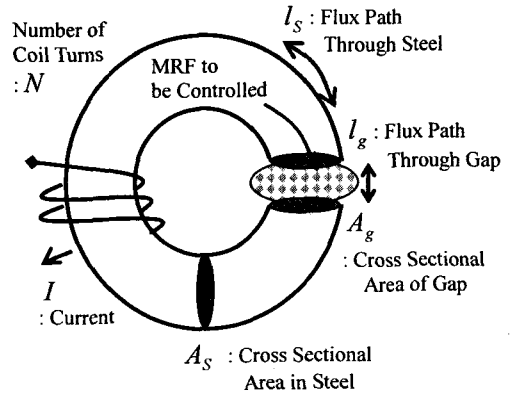


Figure 7. Magnetic Circuit of MRF Device [Weiss et al., 1993]

properties and the solenoid dimensions. Substituting Eqs. (17) and (18) into Eq. (16), we obtain

$$\frac{k_L I^*}{l_g \beta \tau_y^*} \left( \frac{d\tau_y}{dt} \right)^* N^3 + k_R I^* N + (R_V^* + R_F) I^* - V_S^* \leq 0 \quad (19)$$

which offers a guideline for selection of the solenoid coils and determination of the solenoid dimensions. The allowable range of  $N$  then reduces to

$$0 < N \leq \sqrt[3]{\frac{-q + \sqrt{q^2 + 4p^3}}{2}} + \sqrt[3]{\frac{-q - \sqrt{q^2 + 4p^3}}{2}} \quad (20)$$

where  $q = -\frac{l_g \beta \tau_y^*}{k_L I^*} ((R_V^* + R_F) I^* - V_S^*)$  and

$$p = \frac{l_g \beta \tau_y^*}{3} \frac{k_R}{\left( \frac{d\tau_y}{dt} \right)^* k_L}$$

### Typical Design Procedure

Based on the previous analysis of the magnetic and electric circuits, we suggest the following typical design procedure.

1. Determine the number of coil turns,  $N$ , from Eq. (20).
2. Determine the flux path length in MRF,  $l_g$ , from Eq. (13).
3. Select the area ratio of  $\frac{A_g}{A_S}$  from Eq. (12).
4. The cross sectional area of gap,  $A_g = l \cdot w$ , can then be determined, considering the desired controllable force, e.g. the pressure drop  $\Delta P$  in Eq. (5) or the resisting force  $F$  in Eq. (6).

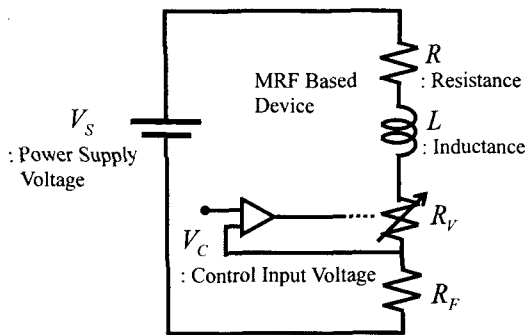


Figure 8. Electric Circuit of MRF Device with Current Amplifier [Maslen et al., 1989]

## 5. Conclusions

The mechanisms which give rise to the yield stress and slew rate limitations have been explored in some detail considering the magnetic and electric circuits of MRF device. It was found that the yield stress limitation is due to the magnetic saturation and finite power supply voltage, and the slew rate limitation is due to the magnet coil inductance and finite power supply voltage. From the theoretical developments, the theoretical upper bound of the number of coil turns is obtained. And finally, a design procedure was formulated to achieve the desired maximum yield stress and the desired maximum yield stress slew rate for the predetermined power supply voltage.

A rigorous verification of the theoretical developments needs extensive experiments, including identification of the unknown and nonlinear behaviors of MRF, is beyond the scope of this work and is left as a future work.

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